



RN1422TE85LF Information



For Reference Only

Part Number RN1422TE85LF

Manufacturer Toshiba Semiconductor and Storage Category Discrete Semiconductor Products

Transistors - Bipolar (BJT) - Single, Pre-Biased

Description TRANS PREBIAS NPN 200MW SMINI

Package TO-236-3, SC-59, SOT-23-3

For the pricing/inventory/lead time, please contact

us

Website: https://www.heisener.com E-mail: salesdept@heisener.com



Request a Quote

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.









RN1422TE85LF Specifications

Manufacturer Part Number	RN1422TE85LF
Manufacturer	Toshiba Semiconductor and Storage
Category	Discrete Semiconductor Products
	Transistors - Bipolar (BJT) - Single, Pre-Biased
Package	TO-236-3, SC-59, SOT-23-3
Series	-
Transistor Type	NPN - Pre-Biased
Current - Collector (Ic) (Max)	800mA
Voltage - Collector Emitter Breakdown (Max)	50V
Resistor - Base (R1) (Ohms)	2.2k
Resistor - Emitter Base (R2) (Ohms)	2.2k
DC Current Gain (hFE) (Min) @ Ic, Vce	65 @ 100mA, 1V
Vce Saturation (Max) @ Ib, Ic	250mV @ 1mA, 50mA
Current - Collector Cutoff (Max)	500nA
Frequency - Transition	300MHz
Power - Max	200mW
Mounting Type	Surface Mount
Package / Case	TO-236-3, SC-59, SOT-23-3
Supplier Device Package	S-Mini
	Report errors?

RN1422TE85LF Guarantees



Quality Guarantees

We provide 90 days warranty. *

If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction.

Our experienced sales team and tech support team back our services to satisfy all our customers.

RN1422TE85LF Payment Methods



















RN1422TE85LF Shipping Methods













If you have any question about RN1422TE85LF, please do not hesitate to contact us!

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